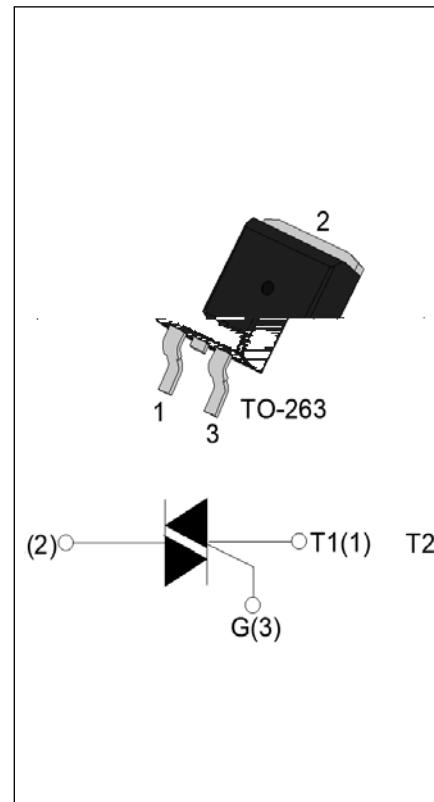


**DESCRIPTION:**

The T1210H-8E triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Compared to traditional triacs, T1210H-8E provides a very high switching capability up to junction temperatures of 150°C. It can be driven directly through the MCU I/O port. Package TO-263 is RoHS compliant.

**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
$V_{DRM}/V_{RRM}$	800	V
$I_{GT\text{ I/II/III}}$	10/10/10	mA

**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	°C
Operating junction temperature range	$T_j$	-40-150	°C
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	800	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	800	V
RMS on-state current ( $T_c \leq 130^\circ\text{C}$ )	$I_{T(RMS)}$	12	A
Non repetitive surge peak on-state current (full cycle , $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	120	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		132	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	72	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2I_{GT}$ , $f=100\text{Hz}$ , $T_j=150^\circ\text{C}$ )	$dI/dt$	100	$\text{A}/\mu\text{s}$
Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=150^\circ\text{C}$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=150^\circ\text{C}$ )	$P_{G(AV)}$	1	W

Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25^\circ\text{C}$ ; non-repetitive, off-state; FIG.8)	$V_{pp}$	4	kV

ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12\text{V}$ $R_L=33$	I - II - III	MAX.	10	mA
$V_{GT}$		I - II - III	MAX.	1	V
$V_{GD}$	$V_D=V_{DRM}$ $T_j=150^\circ\text{C}$ $R_L=3.3\text{K}$	I - II - III	MIN.	0.2	V
$I_L$	$I_G=1.2I_{GT}$	I - III	MAX.	20	mA
		II		30	
$I_H$	$I_T=500\text{mA}$		MAX.	10	mA
$dV/dt$	$V_D=540\text{V}$ Gate Open $T_j=150^\circ\text{C}$		MIN.	150	V/ $\mu\text{s}$
$(dI/dt)c$	$(dV/dt)c=20\text{V}/\mu\text{s}$ , $T_j=150^\circ\text{C}$		MIN.	1.8	A/ms
$t_{on}$	$I_G=20\text{mA}$ $I_A=200\text{mA}$ $I_R=20\text{mA}$ $T_j=25^\circ\text{C}$	TYP.	3	$\mu\text{s}$	
$t_{off}$			50		

## STATIC CHARACTERISTICS

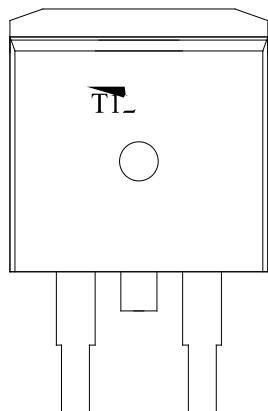
Symbol	Parameter		Value(MAX.)	Unit
$V_{TM}$	$I_{TM}=17\text{A}$	$t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.4
$V_{TO}$	Threshold voltage		$T_j=150^\circ\text{C}$	0.75
$R_D$	Dynamic resistance		$T_j=150^\circ\text{C}$	37
$I_{DRM}$	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25^\circ\text{C}$	5	$\mu\text{A}$
$I_{RRM}$		$T_j=150^\circ\text{C}$	2	mA

## THERMAL RESISTANCES

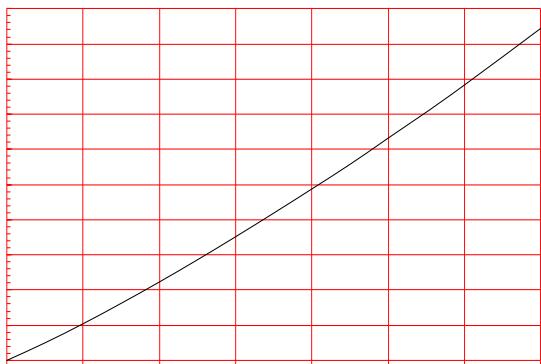
Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	1.3	$^\circ\text{C/W}$
$R_{th(j-a)}$	junction to ambient (AC, in free air, $S=2\text{cm}^2$ )	45	$^\circ\text{C/W}$

**ORDERING INFORMATION**

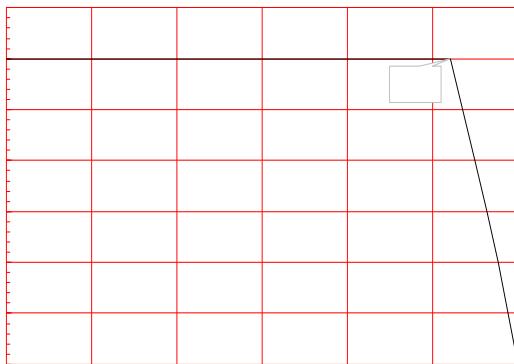
<b>T</b>	<b>12</b>	<b>10</b>	<b>H</b>	<b>-8</b>	<b>E</b>	<b>-/</b>
Triacs						Blank:Tube -TR:Tape & Reel
	<u><math>I_{T(RMS)}:12A</math></u>					
		<u><math>I_{GT1-3} \leq 10mA</math></u>				
				<u>8: <math>V_{DRM} / V_{RRM} \geq 800V</math></u>		
					<u>High junction temperature</u>	

**MARKING**

**FIG.1** Maximum power dissipation versus RMS on-state current



**FIG.2:** RMS on-state current versus case temperature



**FIG.7:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

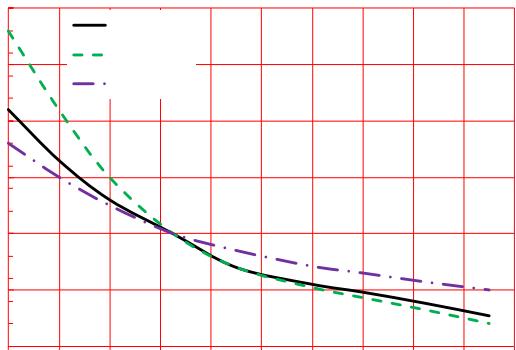
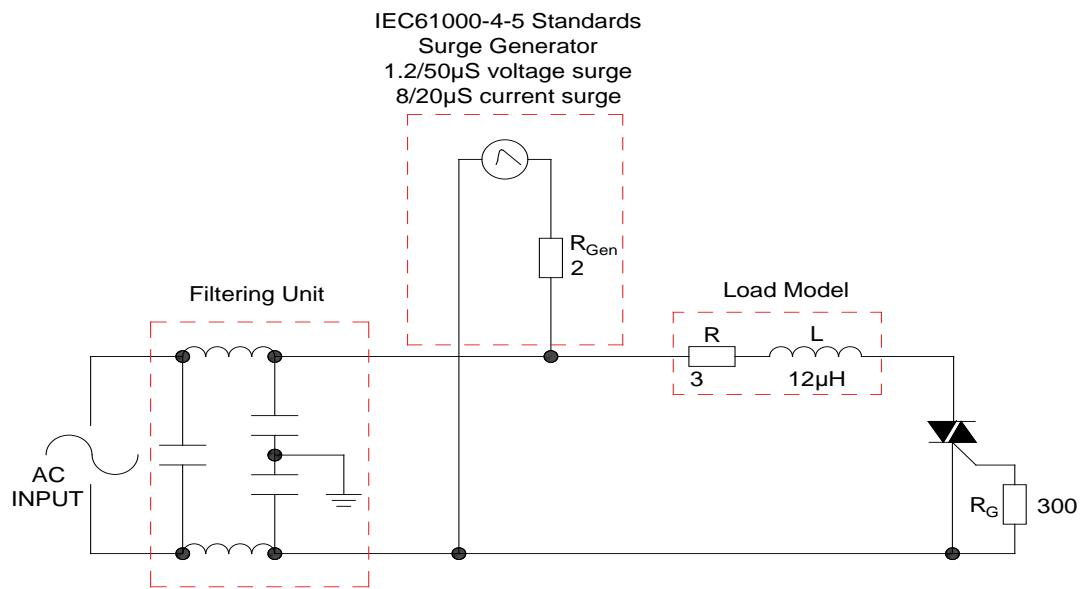


FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



## SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150°C
	-Temperature Max( $T_{s(max)}$ )	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ )to peak)		3°C/sec. Max

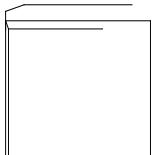
J 0 Tc 0 Tw (T<sub>s(max)</sub>) 66t<sub>d</sub> ( )T<sub>j</sub> EMC ET <>/MCID 22 3>BDC 108 ( 40.011 Td [( )T<sub>j</sub> /C2\_1 1 Tf 0.557 0 Td <0107>T<sub>j</sub> /TT3

**ORDERING INFORMATION**

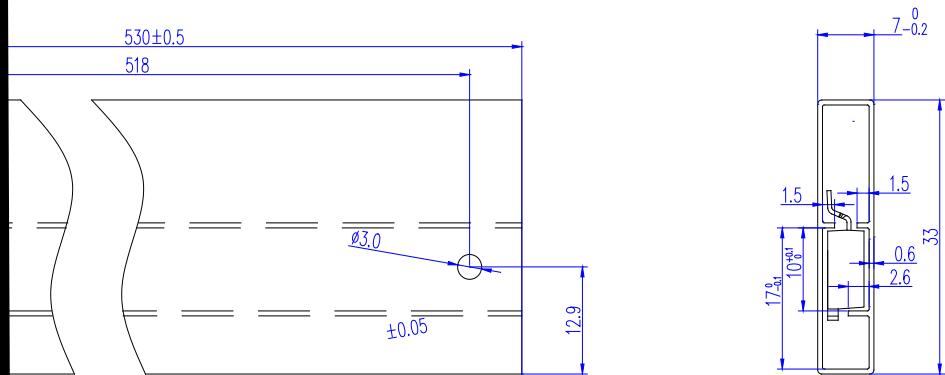
Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
T1210H-8E	800	10	TO-263	50	Tube
T1210H-8E-TR				800	Tape & Reel

**Document Revision History**

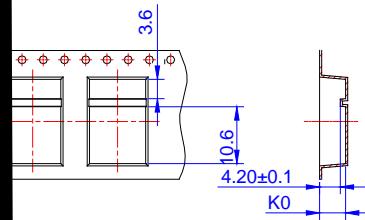
Date	Revision	Changes

**PACKAGE MECHANICAL DATA**

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.37		0.378
D	2.40			0.094		
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G			1.50			
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0		0.25			
M	1.25		1.35			



OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TUBE	50	1,000	5,000



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	23.70	24.00	24.30	0.933	0.945	0.957
E	1.65	1.75	1.85	0.065	0.069	0.073
F	11.40	11.50	11.60	0.449	0.453	0.457
D0	-	1.50	1.60	-	0.059	0.063
D1	-	1.50	1.60	-	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	15.90	16.00	16.10	0.626	0.630	0.634
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	10.80	10.90	11.00	0.425	0.429	0.433
B0	16.20	16.30	16.40	0.638	0.642	0.646
K0	4.80	4.90	5.00	0.189	0.193	0.197
t	0.35	0.40	0.45	0.014	0.016	0.018

